

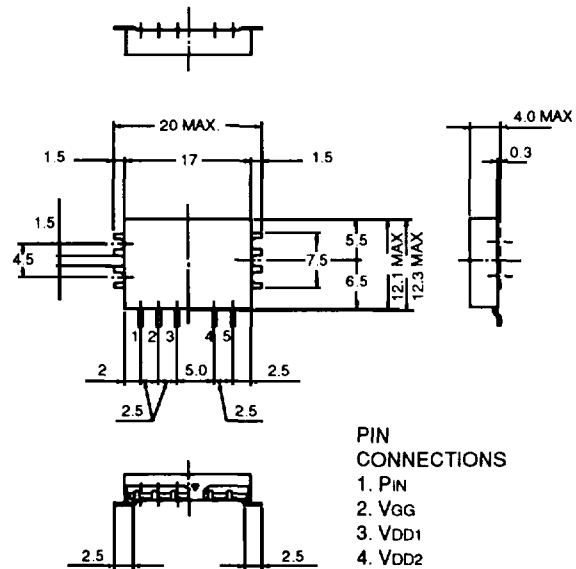
FEATURES

- **LOW DISSIPATIVE CURRENT:**
Total Current $I_{DD} = 330$ mA (Typ.) at $P_{OUT} = 30.0$ dBm
- **HIGH EFFICIENCY:**
Total Efficiency, $\eta_T = 63\%$ (Typ.) at P_{OUT} Maximum
- **SMALL SIZE**

DESCRIPTION

The MC-5950 is a two stage GaAs Multi-Chip Integrated Circuit (MCIC), designed to be used as the Power Amplifier in a cellular portable or handheld application. Its optimum frequency range of 925-942 MHz makes it ideal for cellular analog phones for use in Japan. This device has similar performance in the 902 - 928 MHz band (ISM) and is therefore suitable for Part 15 applications. With separate access provided to both drain supplies, the output power can be effectively controlled. With over 1 Watt output power, excellent efficiency and small size, this MCIC has advantages for a variety of portable wireless applications.

OUTLINE DIMENSIONS (Units in mm)



Note:

1. Lead dimensions 0.25 x 0.5
2. Tolerance of lead pitch ± 0.3

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$)

PART NUMBER PACKAGE OUTLINE			MC-5950		
SYMBOLS	PARAMETERS AND CONDITIONS ¹	UNITS	MIN	TYP	MAX
f	Frequency	MHz	925		942
P_{OUT1}	Output Power 1, $P_{IN} = 6$ dBm, $V_{DD1} = V_{DD2} = 5.8$ V, $V_{GG} = -5.0$ V	dBm	30.8	31.2	
P_{OUT2}	Output Power 2, $P_{IN} = 6$ dBm, $V_{DD1} = 0$ V, $V_{DD2} = 5.8$ V, $V_{GG} = -5.0$ V	dBm		3.0	6.0
I_{DD2}	Total Current, $P_{IN} = 6$ dBm, $P_{OUT} = 30.4$ dBm, $V_{DD1} \leq 5.8$ V, $V_{DD2} = 5.8$ V, $V_{GG} = -5.0$ V	mA		330	370
2fo	Harmonics, $P_{IN} = 6$ dBm, $P_{OUT} = 30.4$ dBm, $V_{DD1} \leq 5.8$ V, $V_{DD2} = 5.8$ V, $V_{GG} = -5.0$ V	dBc		-45	-40
3fo	Harmonics, $P_{IN} = 6$ dBm, $P_{OUT} = 30.4$ dBm, $V_{DD1} \leq 5.8$ V, $V_{DD2} = 5.8$ V, $V_{GG} = -5.0$ V	dBc		-45	-40
4fo	Harmonics, $P_{IN} = 6$ dBm, $P_{OUT} = 30.4$ dBm, $V_{DD1} \leq 5.8$ V, $V_{DD2} = 5.8$ V, $V_{GG} = -5.0$ V	dBc		-45	-40
I_{GG2}	Gate Current, $P_{IN} = 6$ dBm, $P_{OUT} = 30.4$ dBm, $V_{DD1} \leq 5.8$ V, $V_{DD2} = 5.8$ V, $V_{GG} = -5.0$ V	mA		1.0	3.0
VSWR	Input VSWR, $P_{OUT} = +30.4$ dBm, $V_{DD} = 5.8$ V			2:1	
	Stability Against Load Fluctuation, $P_{IN} = 6$ dBm, $P_{OUT} \geq 30.8$ dBm, $V_{GG} = -5.0$ V, $Z_s = 50 \Omega$, ALL PHASE, Load Time = 30 s, $V_{DD1} = V_{DD2} = 8.0$ V, LOAD VSWR = 20:1		No characteristic change. Frequency, Output Power 1, 2, Total Current, Harmonics, Gate Current, Input VSWR		

Notes:

1. $V_{GG} = \pm 0.2$ V, $Z_s = Z_L = 50 \Omega$.
2. $I_{DD} = I_{DD1} + I_{DD2}$

ABSOLUTE MAXIMUM RATINGS¹ ($T_A = 25^\circ\text{C}$)

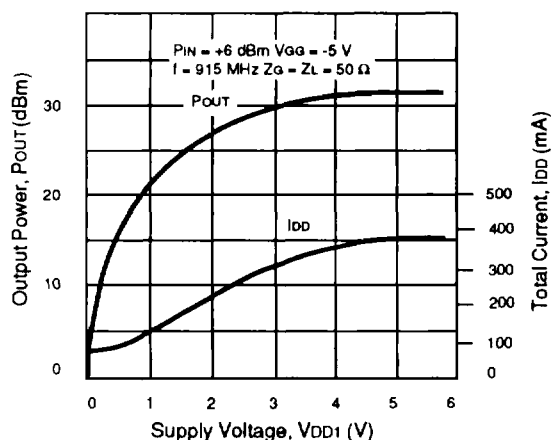
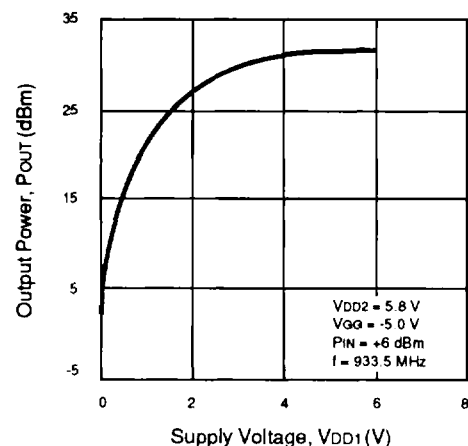
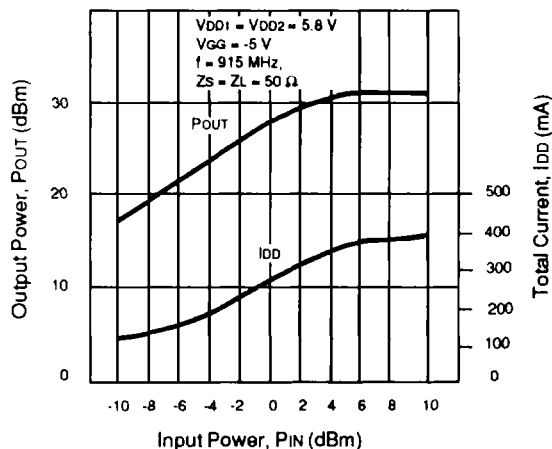
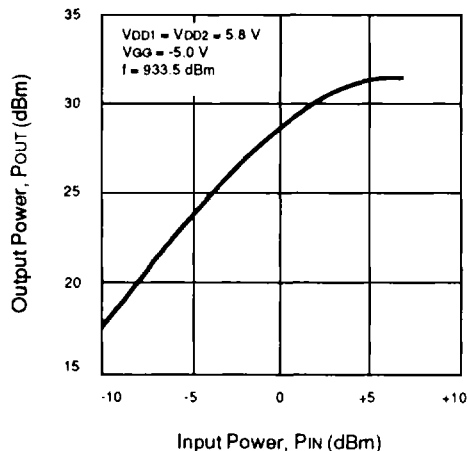
SYMBOLS	PARAMETERS	UNITS	RATINGS
VDD1, 2 ²	Supply Voltage 1, 2	V	10
VGG	Supply Voltage 3	V	-6
PIN	Input Power	dBm	12
TC(OP)	Operating Case Temperature	$^\circ\text{C}$	-30 to +90
TSTG	Storage Temperature	$^\circ\text{C}$	-30 to +120

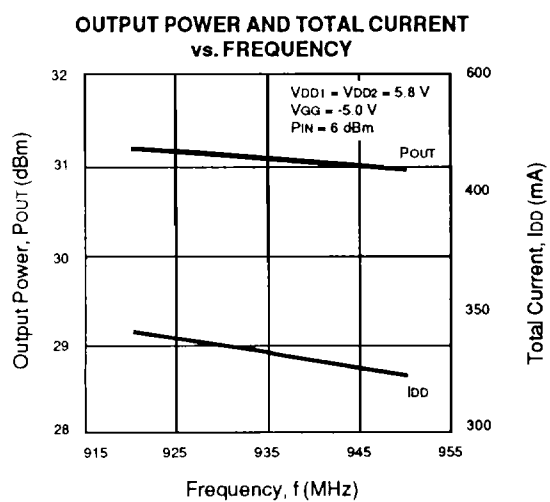
Notes:

- Operation in excess of any one of these parameters may result in permanent damage.
- VGG = -5 V.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETERS	UNITS	MIN	TYP	MAX
VDD1	Supply Voltage 1	V			5.8
VDD2	Supply Voltage 2	V	5.0	5.8	7.0
VGG	Supply Voltage 3	V	-4.8	-5.0	-5.2
PIN	Input Power	dBm		6	7

TYPICAL PERFORMANCE CURVES ($T_A = 25^\circ\text{C}$)**OUTPUT POWER AND TOTAL CURRENT vs SUPPLY VOLTAGE****OUTPUT POWER vs. SUPPLY VOLTAGE****OUTPUT POWER AND TOTAL CURRENT vs. INPUT POWER****OUTPUT POWER vs. INPUT POWER**



EQUIVALENT CIRCUIT

